

SLOVENSKI STANDARD SIST EN ISO 23131:2023

01-januar-2023

Elipsometrija - Načela (ISO 23131:2021)

Ellipsometry - Principles (ISO 23131:2021)

Ellipsometrie - Grundlagen (ISO 23131:2021)

ITEN STANDARD PREVIE

Ellipsométrie - Principes (ISO 23131:2021)

Ta slovenski standard je istoveten z: EN ISO 23131:2022

https://standards.iteh.ai/catalog/standards/sist/eff45e6f-3cfc-47be-b430-eecdaeb9ab01/sist-

en-iso-23131-202.

ICS:

17.020 Meroslovje in merjenje na splošno

Metrology and measurement in general

SIST EN ISO 23131:2023

en,fr,de



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SIST EN ISO 23131:2023

EUROPEAN STANDARD NORME EUROPÉENNE EUROPÄISCHE NORM

EN ISO 23131

November 2022

ICS 17.020

English Version

Ellipsometry - Principles (ISO 23131:2021)

Ellipsométrie - Principes (ISO 23131:2021)

Ellipsometrie - Grundlagen (ISO 23131:2021)

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EUROPEAN COMMITTEE FOR STANDARDIZATION COMITÉ EUROPÉEN DE NORMALISATION EUROPÄISCHES KOMITEE FÜR NORMUNG

CEN-CENELEC Management Centre: Rue de la Science 23, B-1040 Brussels

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European foreword

The text of ISO 23131:2021 has been prepared by Technical Committee ISO/TC 107 "Metallic and other inorganic coatings" of the International Organization for Standardization (ISO) and has been taken over as EN ISO 23131:2022 by Technical Committee CEN/TC 262 "Metallic and other inorganic coatings, including for corrosion protection and corrosion testing of metals and alloys" the secretariat of which is held by BSI.

This European Standard shall be given the status of a national standard, either by publication of an identical text or by endorsement, at the latest by May 2023, and conflicting national standards shall be withdrawn at the latest by May 2023.

Attention is drawn to the possibility that some of the elements of this document may be the subject of patent rights. CEN shall not be held responsible for identifying any or all such patent rights.

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INTERNATIONAL STANDARD

ISO 23131

First edition 2021-04

Ellipsometry — Principles

Ellipsométrie — Principes

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Reference number ISO 23131:2021(E) ISO 23131:2021(E)

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Published in Switzerland

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Foreword

ISO (the International Organization for Standardization) is a worldwide federation of national standards bodies (ISO member bodies). The work of preparing International Standards is normally carried out through ISO technical committees. Each member body interested in a subject for which a technical committee has been established has the right to be represented on that committee. International organizations, governmental and non-governmental, in liaison with ISO, also take part in the work. ISO collaborates closely with the International Electrotechnical Commission (IEC) on all matters of electrotechnical standardization.

The procedures used to develop this document and those intended for its further maintenance are described in the ISO/IEC Directives, Part 1. In particular, the different approval criteria needed for the different types of ISO documents should be noted. This document was drafted in accordance with the editorial rules of the ISO/IEC Directives, Part 2 (see www.iso.org/directives).

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For an explanation of the voluntary nature of standards, the meaning of ISO specific terms and expressions related to conformity assessment, as well as information about ISO's adherence to the World Trade Organization (WTO) principles in the Technical Barriers to Trade (TBT), see <u>www.iso.org/</u> iso/foreword.html.

This document was prepared by Technical Committee ISO/TC 107, *Metallic and other inorganic coatings*.

Any feedback or questions on this document should be directed to the user's national standards body. A complete listing of these bodies can be found at <u>www.iso.org/members.html</u>.

Introduction

The ellipsometry measuring method is a phase-sensitive reflection technique using polarized light in the optical far-field. Over a long time, ellipsometry has been established as a non-invasive measuring method in the field of semiconductor technology — especially within the integrated production — in the first instance as a single-wavelength, then as a multiple-wavelength and later as a spectroscopic measuring method.

By means of ellipsometry, optical or dielectric constants of any material as well as the layer thicknesses of at least semi-transparent layers or layer systems can be determined. Ellipsometry is an indirect measuring method, the analysis of which is based on model optimization. The measurands, which differ according to the procedural principle, are converted into the ellipsometric factors Ψ (Psi, amplitude information) and Δ (Delta, phase information), based on which the physical target figures of interest (optical or dielectric constants, layer thicknesses) will then be determined by means of a parameterized fit.

Ellipsometry shows a high precision regarding the ellipsometric transfer quantities Ψ and Δ , which can be equivalent to a layer thickness sensitivity of 0,1 nm for ideal layer substrate systems. As a result, the measuring method can verify even the slightest discrepancies in the surface characteristics. This is closely linked to the homogeneity and the isotropy of the material surface. In order to achieve high precision, carrying out measurements at the exact same measuring point is a prerequisite for inhomogeneous materials. The same applies to the orientation of the incident plane relative to the material surface for anisotropic materials.

The absolute accuracy, e.g. of layer thickness values, substantially depends on the quality of the chosen model for describing the material surface. For ideal layer substrate systems, such as SiO_2 (ideal transparent layer) on a Si wafer (nearly atomically smooth substrate surface with homogeneous and isotropic material properties), the accuracy of the layer thickness can indeed reach the precision values, since the model describes the reality of the layer substrate system in an ideal manner. For inhomogeneous, anisotropic, contaminated, multi-component, damaged, imperfect or rough surfaces or layers, the accuracy of the layer thickness determination can be significantly lower and generally depends on the quality of the chosen model.

Despite these limitations, ellipsometry is a powerful procedure, which either enables material fingerprints (without modelling) or which allows a model-based determination of optical and dielectric constants (to the nearest 0,001) or of layer thicknesses (to the nearest 0,1 nm) within a broad layer thickness range of approximately 0,1 nm up to approximately 10 μ m (in special cases exceeding 100 μ m).